

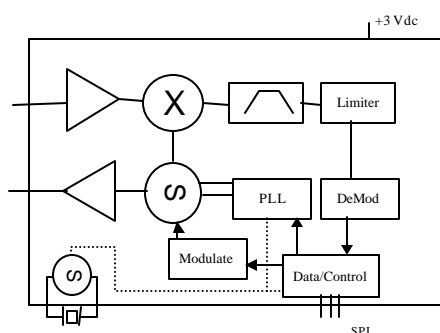
## Features

- High integration to minimize total system costs
- Contains LNA, Mixers, Filters, Limiters, Demod, Mod., PA, PLL, VCO, Ref. Osc. Data Retiming and SPI port
- Data rates to 28.8 Kbits/sec (with full Manchester Encoding on chip)
- Direct connection to microprocessor
- Single Rail Operation
- Programmable power levels, frequency, Tx/Rx/Stdby
- Wide Supply rail 2.4V to 3.3V @ 22mA during operation

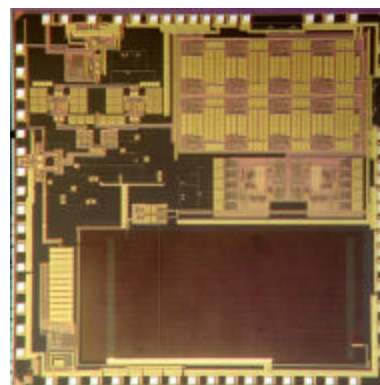
## Description

The JS Technologies JST-AWICS09325 is a single ASIC transceiver for use in digital data and time division full-duplex voice applications. Direct microprocessor connections for control and data transfer eliminate the need for costly off chip components. The JST-AWICS09325 is ideally suited for use in battery powered wireless applications in conjunction with microprocessors for data communication and a Codec for voice.

## Functional Schematic



Package Option – inquire for options



## RF Electrical Specification @ + 25°C Ambient

Parameter	Test Condition	Frequency	Units	Min	Typical	Max
Rx Sensitivity		300– 928 MHz	dBm		-95	
1dB Compression	Vdd= 3V	300– 928 MHz	dBm		-20	
Input IP3	Vdd = 3V	300– 928 MHz	dBm		-5	
Tx Output power	Vdd = 3V	300– 928 MHz	dBm dBm		+3	
Data Rate, Tx / Rx	Continuous data w/Manchester Encoder		Kbps		28.8	
Adj. Channel rejection		Fc +/- 200KHz	dB		75	
Detection Bandwidth	IQ baseband filter passband		KHz		100	
Control/Data I/O	Serial peripheral interface (SPI). Direct connection to microcontroller/microprocessor		MHz		10	

Web Site: [www.jstcorp.com](http://www.jstcorp.com)

Email: [info@jstcorp.com](mailto:info@jstcorp.com)

## DC Electrical Specifications @ + 25°C Ambient

Parameter	Units	Minimum	Typical	Max
V <sub>DD</sub>	V	2.4	3.0	3.3
Power Supply Current During Tx, Output Power Dependant (915MHz)	mA	16	26	
Power Supply Current (I <sub>DD</sub> ) during Rx (915MHz)	mA	22	28	
Standby Power Consumption	uA		TBD	
Logic level (0) CMOS	V	0		0.7
Logic level (1) CMOS	VOH	1.7		V <sub>DD</sub>
Input Leakage Current	uA			2

Absolute Maximum Ratings<sup>1</sup>

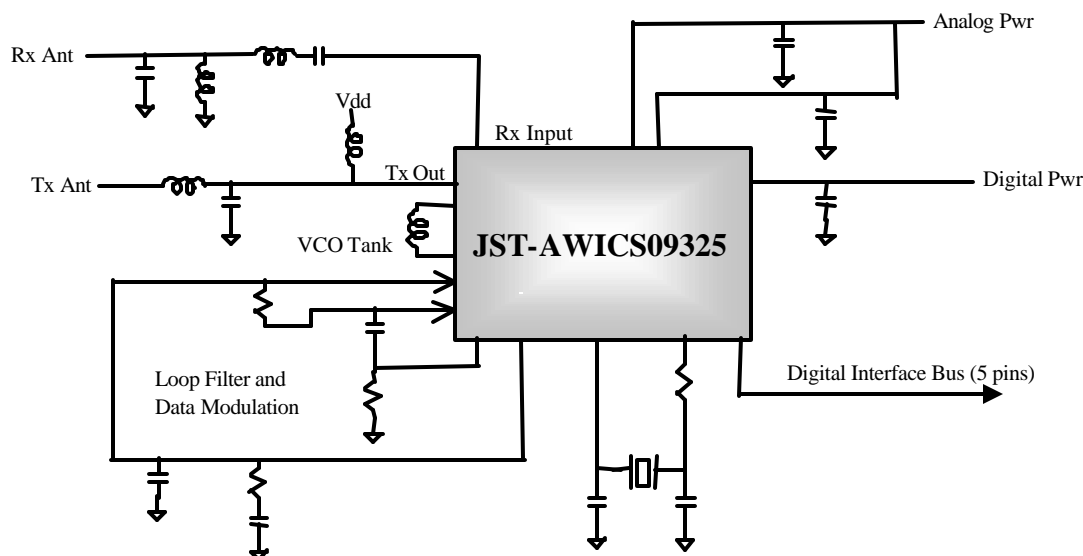
Parameter	Absolute Maximum
Maximum Input Power	-
+ V <sub>DD</sub>	+ 3.6 V
ESD Voltage (Human Body Model)	TBD
Operating Temperature	- 40°C to + 85°C
Storage Temperature	- 40°C to + 150°C

<sup>1</sup> Operation of this Device beyond any of these parameters may cause permanent damage

**Latch-Up:** This chip uses Honeywell's RF-SOI process which is immune to latch-up.

**ESD Protection:** Although this device contains ESD protection circuitry, conventional precautions should be taken to ensure that the Absolute Maximum Ratings are not exceeded.

## Typical Application Schematic



JS Technologies reserves the right to make changes to improve reliability, function or design. JS Technologies does not assume any liability arising out of the application or use of any product or circuit described herein; neither does it convey any license under its patent rights nor the rights of others. This chip was developed in conjunction with the Honeywell Solid State Electronics Center exclusively for JS Technologies Corp.